

# InAsSb photovoltaic detectors

### P16114-011MN P16614-011CN

# Infrared detector with high photosensitivity (up to 10 $\mu$ m band)

The P16114-011MN and P16614-011CN are an infrared detector that have high sensitivity in the spectral band up to 10 µm. This high sensitivity has been achieved due to Hamamatsu unique crystal growth technology and process technology. By using a back-illuminated structure, the photosensitivity has been improved compared to the front-illuminated type. These products are an environmentally friendly infrared detector and do not use lead, mercury, or cadmium, which are substances restricted by the RoHS directive. These products replace conventional products containing these substances.

#### Features

- High sensitivity
- High-speed response
- High shunt resistance
- Compact, surface mount type ceramic package (P16614-011CN)
- Compatible with lead-free solder reflow (P16614-011CN)
- RoHS compliant (lead, mercury, cadmium free)

#### Applications

- Gas detection (SOx, NOx, NH3, O3, etc.)
- Radiation thermometers
- CO2 laser monitor
- Mid infrared spectroscopy
- Option (sold separately)
- Amplifier for infrared detector
- C4159-01

#### Structure

Parameter	P16114-011MN	P16614-011CN	Unit
Window material	None		-
Package	TO-5	Ceramic	-
Photosensitive area	0.7 × 0.7		mm
Field of view	101	86	degrees

#### - Absolute maximum ratings (Ta=25 °C, unless otherwise noted)

Parameter	Symbol	Value	
Reverse voltage	VR	1	V
Operating temperature <sup>*1</sup>	Topr	-40 to +85	°C
Storage temperature*1	Tstg	-40 to +85	°C
Incident light level	Pin	1	W/mm <sup>2</sup>
Soldering temperature	Tsol	240 (once)* <sup>2</sup>	°C

\*1: No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability. \*2: P16614-011CN Reflow soldering, JEDEC J-STD-020 MLS 2, see P.6

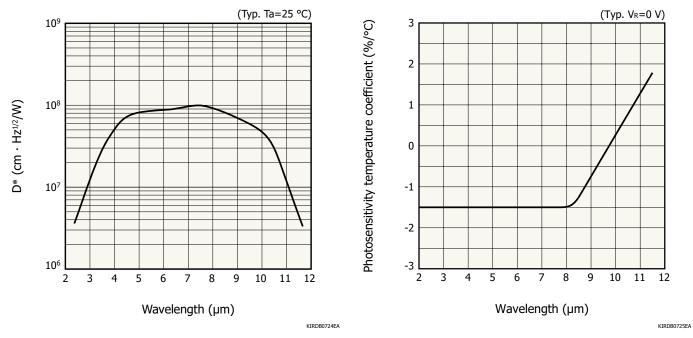
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Photosensitivity temperature characteristics

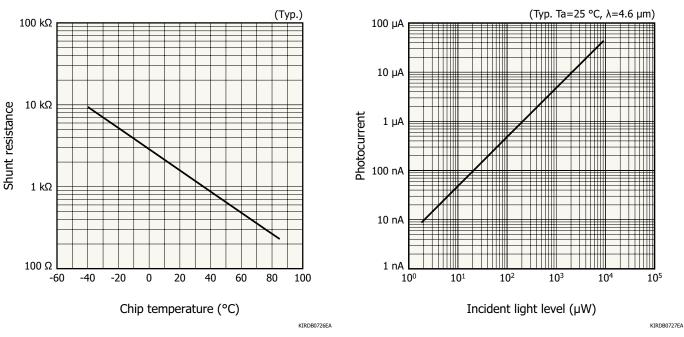
#### Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Peak sensitivity wavelength	λр		-	7.4	-	μm
Cutoff wavelength	λc		9.7	11.0	-	μm
Photosensitivity	S	λ=λp	3.4	5.0	-	mA/W
Shunt resistance	Rsh	VR=10 mV	0.65	1.3	-	kΩ
Terminal capacitance	Ct	VR=0 V, f=1 MHz	-	1.2	-	pF
Detectivity	D*	(λρ, 1200, 1)	4.7 × 10 <sup>7</sup>	$1.0 \times 10^{8}$	-	cm·Hz <sup>1/2</sup> /W
Noise equivalent power	NEP	λ=λp	-	7.1 × 10 <sup>-10</sup>	$9.0 \times 10^{-10}$	W/Hz <sup>1/2</sup>
Rise time	tr	VR=0 V, RL=50 Ω, 10 to 90%	-	3	10	ns

#### Spectral response (D\*)



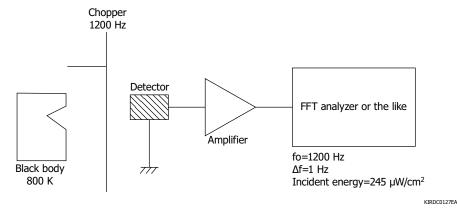




📮 Linearity

Shunt resistance vs. chip temperature

#### Block diagram for characteristic measurement

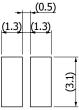




Dimensional outline (unit: mm)

#### P16114-011MN P16614-011CN 2.6 ± 0.2 Photosensitive area 0.7 × 0.7 <u>2.0 ± 0.15</u> Index mark **¢**9.3 ± 0.3 $\phi 8.1 \pm 0.1$ **∳**5.9 ± 0.1 X 2.0 ± 0.15 2.6 ± 0.2 Photosensitive area 0.7 × 0.7 $4.2 \pm 0.2$ $1.8 \pm 0.2$ Photosensitive $0.25 \pm 0.1$ $0.55 \pm 0.1$ $1.3 \pm 0.13$ surface Photosensitive 0.4 max. surface $20 \pm 0.5$ (0.8) (0.85) ф0.45 Lead (0.5) (0.65) φ<u>5.1 ± 0.</u>2 (2.2) (2.2) 1 ① Cathode ① ○ ▶ ○ ② 2 Anode ③ Case

KIRDA0290FA



Recommended land pattern Values in parentheses indicate reference values. KIRDA0285EB

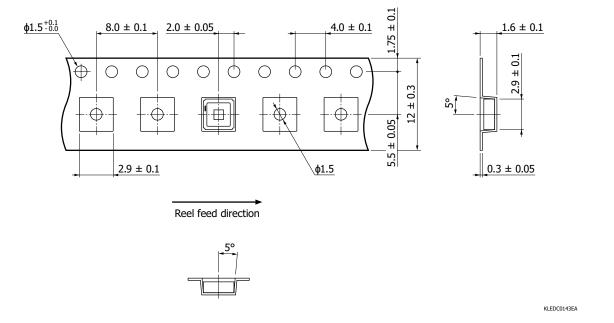
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#### Standard packing specifications (P16614-011CN)

Reel (conforms to JEITA ET-7200)

Outer diameter	Hub diameter	Tape width	Material	Electrostatic characteristics
φ180 mm	ф60 mm	12 mm	PS	Conductive

Embossed tape (unit: mm, material: PS, conductive)



Packing quantity 100 pcs/reel

Packing state

Reel and desiccant in moisture-proof packaging (vacuum-sealed)



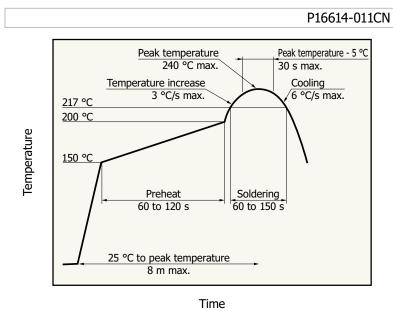
#### Recommended soldering conditions

#### P16114-011MN

· Solder temperature: 260 °C (10 s or less, once)

Solder the leads at a point at least 1 mm away from the package body.

Note: When you set soldering conditions, check that problems do not occur in the product by testing out the condition in advance.



 After unpacking, store it in an environment at a temperature of 5 to 30 °C and a humidity of 60% or less, and perform reflow soldering within 1 year.

· The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. When you set reflow soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- Disclaimer
- Safety consideration
- Surface mount type products
- · Unsealed products
- · Compound opto-semiconductors (photosensors, light emitters)

Technical note

· Compound semiconductor photosensors

The content of this document is current as of May 2024.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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